

A1
cont.
respect to a corresponding one of the column lines, each of said circuits comprising at least one thin film transistor, and one of said at least two circuits of one of the analog buffer circuits is positioned in the same line along said column lines as one of said at least two circuits of another one of the analog buffer circuits.--

IN THE CLAIMS:

Please amend claim 8 as follows.

A2
8. (Amended) An active matrix device according to claim 6 wherein electrical characteristics of said first and second circuits in one of said buffer circuits differ from each other.

26

P